L	Hits	Search Text	DB	Time stamp
Number 1	376	438/259.ccls.	USPAT;	2004/03/06
			US-PGPUB;	11:27
			EPO; JPO; DERWENT;	
			IBM_TDB	
2	1656	438/270.ccls.	USPAT;	2004/03/06
			US-PGPUB; EPO; JPO;	08:31
			DERWENT;	
	222	100/070	IBM_TDB	0004/00/06
3	111	438/270.ccls. and drift	USPAT; US-PGPUB;	2004/03/06 09:24
			EPO; JPO;	
			DERWENT;	
4	22	438/271.ccls. and drift	IBM_TDB USPAT;	2004/03/06
•	~~	155, 2, 1, 155251 dild dilli	US-PGPUB;	09:27
			EPO; JPO;	
			DERWENT; IBM TDB	
5	13	438/272.ccls. and drift	USPAT;	2004/03/06
			US-PGPUB; EPO; JPO;	09:39
			DERWENT;	
			IBM_TDB	
6	35	(extended adj trench) and drift	USPAT; US-PGPUB;	2004/03/06 09:32
			EPO; JPO;	09.32
			DERWENT;	
7	121	extended adj trench	IBM_TDB USPAT;	2004/03/06
'	121	extended adj trench	US-PGPUB;	09:37
			EPO; JPO;	
			DERWENT;	
8	18	segmented adj trench	USPAT;	2004/03/06
			US-PGPUB;	09:38
			EPO; JPO; DERWENT;	
			IBM_TDB	
9	3	438/242.ccls. and drift	USPAT;	2004/03/06
			US-PGPUB; EPO; JPO;	09:40
			DERWENT;	
10	137	438/242.ccls.	IBM_TDB USPAT;	2004/03/06
	15,	100, 212.0010.	US-PGPUB;	09:49
			EPO; JPO;	
			DERWENT; IBM TDB	
11	0	gate adj botton adj second adj trench	USPAT;	2004/03/06
			US-PGPUB;	09:49
			EPO; JPO; DERWENT;	
			IBM_TDB	
12	0	gate adj formed adj botton adj second adj trench	USPAT; US-PGPUB;	2004/03/06 09:49
		CT CHCH	EPO; JPO;	09.39
			DERWENT;	
13	0	gate adj formed adj botton adj extended	IBM_TDB USPAT;	2004/03/06
		adj trench	US-PGPUB;	09:50
			EPO; JPO;	
]			DERWENT; IBM TDB	
14	0	gate adj formed adj botton adj deep adj	USPĀT;	2004/03/06
		trench	US-PGPUB;	09:50
			EPO; JPO; DERWENT;	
			IBM_TDB	

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15	1	gate adj formed adj deep adj trench	USPAT; US-PGPUB;	2004/03/06 09:50
			EPO; JPO; DERWENT;	
16	223	anto ndi formod ndi tronch	IBM_TDB USPAT;	2004/03/06
10	223	gate adj formed adj trench	US-PGPUB;	09:51
			EPO; JPO;	
			DERWENT;	
17	22	/	IBM_TDB	2004/02/06
17	32	(gate adj formed adj trench) and drift	USPAT; US-PGPUB;	2004/03/06
			EPO; JPO;	
			DERWENT;	
18	0	acurac adi magian adi anagod adi anart	IBM_TDB USPAT;	2004/03/06
10	U	source adj region adj spaced adj apart adj first adj trench	US-PGPUB;	09:54
		adj 11150 daj cronon	EPO; JPO;	
			DERWENT;	
10	3		IBM_TDB	2004/02/06
19	3	source adj region adj spaced adj apart adj trench	USPAT; US-PGPUB;	2004/03/06
		,	EPO; JPO;	
			DERWENT;	
20	0	20020113263 nn and /mata with daned)	IBM_TDB USPAT;	2004/03/06
20	l U	20020113263.pn. and (gate with doped)	US-PGPUB;	10:23
			EPO; JPO;	
			DERWENT;	
21	0	20020113263 pp. and (gate same doned)	IBM_TDB USPAT;	2004/03/06
21		20020113263.pn. and (gate same doped)	US-PGPUB;	10:23
			EPO; JPO;	
			DERWENT;	
22	2	20020113263.pn. and (gate same	IBM_TDB USPAT;	2004/03/06
22	_	conductivity)	US-PGPUB;	10:59
			EPO; JPO;	
			DERWENT;	
23	1	6673681.pn. and (gate with doped)	USPAT;	2004/03/06
			US-PGPUB;	10:25
			EPO; JPO;	
			DERWENT; IBM TDB	
24	2	6673681.pn. and (gate same doped)	USPAT;	2004/03/06
			US-PGPUB;	12:05
			EPO; JPO; DERWENT;	
			IBM TDB	
25	1	20020113263.pn. and vertical	USPAT;	2004/03/06
			US-PGPUB; EPO; JPO;	11:10
			DERWENT;	
			IBM_TDB	
26	0	(vertical adj (fet or (field adj effect	USPAT;	2004/03/06
		adj transistor))) and ((gaas or (gallium adj arsenide)) adj body)	US-PGPUB; EPO; JPO;	11:12
		aaj azaonitao,, aaj boay,	DERWENT;	
			IBM_TDB	0004/00/00
27	155	(vertical adj (fet or (field adj effect adj transistor))) and (gaas or (gallium	USPAT; US-PGPUB;	2004/03/06 11:23
		adj transistor;;; and (gaas or (gallium adj arsenide))	EPO; JPO;	11.25
			DERWENT;	
20	400	/	IBM_TDB	2004/02/06
28	499	(semiconductor adj body) with ((gaas or (gallium adj arsenide)) or (inp or	USPAT; US-PGPUB;	2004/03/06
		(indium adj phosphide)))	EPO; JPO;	
			DERWENT;	
L			IBM TDB	

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29	21	((semiconductor adj body) with ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)))) and trench	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:25
	ŀ		IBM_TDB	
30	499	(semiconductor adj body) with ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:26
31	36	438/259.ccls. and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:31
32	118	438/270.ccls. and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:34
33	19	438/271.ccls. and ((gaas or (gallium adjarsenide)) or (inp or (indium adjaphosphide)) or iiiv)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:35
34	8	438/272.ccls. and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:39
35	24	passivation adj stack	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:41
36	44	plurality adj passivation	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:43
37	57	(double or dual) adj passivation	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 11:46
38	43	(trench) adj passivation	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/03/06 11:48
39	74	(trench) near passivation	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/03/06 11:48
40	2	6277751.pn.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/03/06 12:48
41	0	4816884.pn. and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 12:49
42	0	4824793.pn. and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/06 12:50

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43	0	4833516.pn. and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	USPAT; US-PGPUB; EPO; JPO;	2004/03/06 12:50
			DERWENT; IBM TDB	
44	0	4661832.pn. and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 12:50
46	511	drift and trench and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 12:56
47	22	drift and trench and ((gaas or (gallium adj arsenide)) or (inp or (indium adj phosphide)) or iiiv) and (depletion adj mode)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/06 13:26
48	3	drift and trench and (n adj channel adj depletion adj mode)	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/03/06 13:27
-	64	double adj trench	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/03/05 18:36
-	1420	(trench adj trench) and 257/\$.ccls.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/05 15:46
-	16	(trench adj "within" adj trench) and 257/\$.ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/03/05 15:48
_	. 0	(trench adj "within" adj trench) and (drift adj (layer or film))	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/05 15:49
-	47	(trench adj trench) and (drift adj (layer or film))	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/03/05 15:52
	0	(dual adj trench) and (drift adj (layer or film))	DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/03/05 15:53
-	354	(trench) and (drift adj (layer or film))	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/03/05 16:05
_	578	(gate adj trench) and 257/\$.ccls.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/03/05 16:08
-	0	(double adj recess adj substrate) and 257/\$.ccls.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/03/05 16:09
			DERWENT; IBM_TDB	

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-	0	double adj recess adj substrate	USPAT;	2004/03/05
			US-PGPUB; EPO; JPO;	16:09
	·		DERWENT;	
			IBM_TDB	
_	0	double adj recessed adj substrate	USPAT;	2004/03/05
			US-PGPUB;	16:09
			EPO; JPO; DERWENT;	
1			IBM TDB	
_	0	dual adj recessed adj substrate	USPAT;	2004/03/05
ţ			US-PGPUB;	16:09
			EPO; JPO; DERWENT;	
			IBM TDB	
-	0	multiple adj recessed adj substrate	USPAT;	2004/03/05
1			US-PGPUB;	16:10
			EPO; JPO;	
			DERWENT; IBM TDB	
-	5	multiple adj groove adj substrate	USPAT;	2004/03/05
			US-PGPUB;	16:10
Į			EPO; JPO;	
j			DERWENT; IBM TDB	
_	0	double adj groove adj substrate	USPAT;	2004/03/05
			US-PGPUB;	16:11
1			EPO; JPO;	
			DERWENT; IBM TDB	
_	0	double adj mesa adj substrate	USPAT;	2004/03/05
			US-PGPUB;	16:11
			EPO; JPO;	
			DERWENT; IBM TDB	
_	104	double adj damascene	USPAT;	2004/03/05
			US-PGPUB;	16:14
			EPO; JPO;	
			DERWENT; IBM TDB	
	126	(first adj trench) and (second adj	USPAT;	2004/03/05
		trench) and drift	US-PGPUB;	16:24
			EPO; JPO;	
			DERWENT;	
_	8	(upper adj trench) and (lower adj trench)	IBM_TDB USPAT;	2004/03/05
1		and drift	US-PGPUB;	16:25
			EPO; JPO;	
			DERWENT; IBM TDB	
-	1	(trench adj first adj width) and drift	USPAT;	2004/03/05
	_		US-PGPUB;	16:26
			EPO; JPO;	
			DERWENT; IBM TDB	
-	О	(trench adj first adj length) and drift	USPAT;	2004/03/05
			US-PGPUB;	16:26
			EPO; JPO;	
			DERWENT; IBM TDB	
_	2	trench adj first adj length	USPAT;	2004/03/05
			US-PGPUB;	16:27
			EPO; JPO;	
			DERWENT;	.
-	51	trench adj first adj width	IBM_TDB USPAT;	2004/03/05
			US-PGPUB;	16:33
			EPO; JPO;	
			DERWENT;	
	L	<u> </u>	IBM TDB	

•				
_	0	trench adj "having" adj first adj width	USPAT;	2004/03/05
	ļ		US-PGPUB;	16:33
			EPO; JPO; DERWENT;	
			IBM TDB	
_	346	recessed adj trench	USPAT;	2004/03/05
			US-PGPUB;	16:35
			EPO; JPO;	
			DERWENT;	
	102	(magagad adi trongh) and 257/6 ggls	IBM_TDB USPAT;	2004/03/05
-	193	(recessed adj trench) and 257/\$.ccls.	US-PGPUB;	16:44
	j		EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	33	(vertical adj fet) and drift	USPAT;	2004/03/05
			US-PGPUB;	16:46
			EPO; JPO; DERWENT;	
			IBM TDB	
_	169	(vertical adj fet) and trench	USPAT;	2004/03/05
			US-PGPUB;	16:56
İ			EPO; JPO;	
			DERWENT;	
	20	/**********	IBM_TDB USPAT;	2004/02/05
-	28	(vertical adj fet) and (deep adj trench) and (shallow adj trench)	US-PGPUB;	2004/03/05 16:57
1		and (Sharrow ad) cremen,	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	963		USPAT;	2004/03/05
]	trench) and 257/\$.ccls.	US-PGPUB;	16:58
]		EPO; JPO; DERWENT;	
			IBM TDB	
_	371	((deep adj trench) with (shallow adj	USPAT;	2004/03/05
		trench)) and 257/\$.ccls.	US-PGPUB;	17:04
			EPO; JPO;	
			DERWENT;	
_	5.6	((deep adj trench) near (shallow adj	IBM_TDB USPAT;	2004/03/05
		trench)) and 257/\$.ccls.	US-PGPUB;	16:59
			EPO; JPO;	
			DERWENT;	
	10		IBM_TDB	0004/02/05
-	18	((deep adj trench) with (shallow adj trench)) and 257/\$.ccls. and drift	USPAT; US-PGPUB;	2004/03/05 18:18
		crench); and 25//\$.ccis. and drift	EPO; JPO;	10.10
			DERWENT;	
	[IBM_TDB	
-	140	(gate adj trench) and 257/\$.ccls. and	USPAT;	2004/03/05
		drift	US-PGPUB;	18:30
			EPO; JPO; DERWENT;	
			IBM TDB	
_	0	(first adj trench adj "within" adj second	USPAT;	2004/03/05
		adj trench) and 257/\$.ccls. and drift	US-PGPUB;	18:31
1			EPO; JPO;	
			DERWENT; IBM TDB	
-		first adj trench adj "within" adj second	USPAT;	2004/03/05
		adj trench	US-PGPUB;	18:31
			EPO; JPO;	
			DERWENT;	
		finat add to and add accord add to a a de	IBM_TDB	2004/02/05
-	'	first adj trench adj second adj trench	USPAT; US-PGPUB;	2004/03/05 18:31
			EPO; JPO;	10.31
			DERWENT;	
			IBM TDB	

				T
-	368	(first adj trench) near (second adj	USPAT;	2004/03/05
		trench)	US-PGPUB;	18:32
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	40	((first adj trench) near (second adj	USPAT;	2004/03/05
		trench)) and drift	US-PGPUB;	18:35
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	0	double adj etched adj trench	USPAT;	2004/03/05
			US-PGPUB;	18:36
	}		EPO; JPO;	
	j		DERWENT;	
			IBM TDB]
_	141	double near trench	USPAT;	2004/03/05
			US-PGPUB;	18:41
		·	EPO; JPO;	
			DERWENT;	
			IBM TDB	1
_	16	interconnected adj trench	USPAT;	2004/03/05
			US-PGPUB;	18:54
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	499	257/302.ccls.	USPAT;	2004/03/05
			US-PGPUB;	18:55
			EPO; JPO;	[·
			DERWENT;	
		•	IBM TDB	